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Ultrasonic-assisted spray pyrolysis technique for synthesis of transparent S-doped TiO₂ thin film

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Abstract

Nanostructured TiO_2 and S-doped TiO_2 thin films with high transparency were prepared on glass substrate through ultrasonic-assisted spray pyrolysis technique. The effect of sulfur doping on morphological, optical, and structural properties of TiO_2 was studied by scanning electron microscopy (SEM), X-ray diffraction (XRD), Raman spectroscopy, FTIR, photoluminescence spectroscopy, and UV-visible absorption spectroscopy techniques. Because of the high uniformity and monodispersity of the prepared TiO_2 and S-doped TiO_2 thin films, these samples have high visible-light transparency of about 81.89% and 69.73%, respectively. Both the TiO_2 and S-doped TiO_2 thin films have anatase crystal structure; however, introduction of the S dopant in the lattice of TiO_2 creates some oxygen vacancies and structural defects in the S-doped TiO_2 , this sample has lower electron-hole recombination rate than undoped TiO_2 . Furthermore, sulfur doping results in the band-gap narrowing of TiO_2 . Compared to the undoped TiO_2 sample, suppression of the electron-hole recombination and band-gap narrowing in the S-doped TiO_2 thin films result in the enhancement of its visible-light photocatalytic activity.

Keywords S doping · Titanium dioxide · Transparent · Ultrasonic · Spray pyrolysis

Introduction

Presence of organic dyes in industrial and textile wastewaters has raised significant environmental concerns. Furthermore, water pollution with organic dyes is a serious threat to the living organisms because of their toxicity and carcinogenic nature. Currently available methods for water treatment from dye pollutants are microbial degradation [1], photocatalytic degradation [2], adsorption [3, 4], advanced oxidation [5], filtration [6, 7], and sonolysis [8]. Among these methods, photocatalytic degradation is the most effective and simple approach for cleaning of organic dyes from polluted water and wastewater.

Among the various semiconductor photocatalysts like WO₃, ZnWO₄, ZnO, and BiTiO₃ [9–11], undoubtedly TiO₂ is the most commonly used one for the photocatalytic degradation of organic contaminants in water owing to its high oxidizing power, non-toxicity, good chemical stability, cheapness, and high photocatalytic activity [12, 13]. The major drawback of TiO_2 is its relatively wide band-gap energy (3.0 to 3.2 eV [14]), which limits its photocatalytic activity to the UV region. Another important factor that has significant effect on the photoactivity of a photocatalyst is the electron-hole recombination rate, and any factor that reduces the electronhole recombination rate will improve the photocatalytic activity [15]. In this regard, numerous methods like sensitizing with semiconductor quantum dots (QDs) or organic dyes [16, 17], doping and codoping with metal and non-metal elements [18, 19], and compositing with carbon nanomaterials [20, 21] have been developed to improve the visible-light photocatalytic activity of TiO₂.

In the case of sulfur doping into the TiO_2 crystal lattice, sulfur can present in more than one oxidation state such as S^{2-}

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(anionic), or S^{6+} (cationic), depending on the synthesis conditions and the precursor type [22]. Furthermore, the elemental S atoms can occupy the substitutional and interstitial sites in the TiO₂ lattice and the mixing of S 3p states with valance band of TiO₂ can cause the band-gap energy to decrease [23]. For these reasons, preparation of S-doped TiO₂, for photocatalytic applications, has attracted increasing attention in recent years [24].

To avoid the expensive and complex separation of the photocatalyst after degradation proses, TiO_2 in the form of thin film on a substrate are preferred to the TiO_2 nanoparticle suspensions. Semiconductor-based photoactive films are deposited on various substrates of metals, ceramics, silicon wafer, and glass in widespread applications such as solar cells, self-cleaning surfaces, hydrogen production, photocatalysis, and air purification [25]. Among these substrates, glass substrate is the most appropriate because it has excellent chemical stability, high transmittance, and low cost. Transparency is an important requirement in consideration of the potential photocatalytic application of coatings on the building and vehicle glass; for these reasons, there is considerable interest on the preparation of transparent photoactive films on glass substrate [26, 27].

Pure and doped TiO₂ thin films have been prepared by a variety of techniques such as mechanical alloying [28], sputtering [29], sol–gel [30], pulsed laser deposition [31], spray pyrolysis [32], and solvothermal [33] methods. However, these techniques suffer from several limitations like use of toxic organometallic reagents, expensive equipment, complex reaction process, and long reaction time. In the present work, pure and S-doped TiO₂ thin films with high monodispersity and transparency were deposited on glass substrate through a simple design based on ultrasonic-assisted spray pyrolysis technique. The visible-light photocatalytic activity of the prepared samples was evaluated by measuring the degradation of methylene blue (MB) under visible-light radiation.

Material and methods

Materials

All chemicals were used without further purification. The following chemicals were used in this work: titanium(IV) butoxide (\geq 97.0% from Sigma-Aldrich), thiourea (\geq 99.0% from Sigma-Aldrich), concentrated hydrochloric acid (37 wt%, Merck), and absolute ethanol (99.5% v/v, Merck).

Preparation of TiO₂ thin films

The schematic illustration of the thin-film deposition system is shown in Fig. 1. At first, TiO_2 sol solution was prepared by dropwise addition of 30 ml ethanolic solution of HCl (0.01 M) into the 30 ml of ethanolic solution of titanium(IV) butoxide

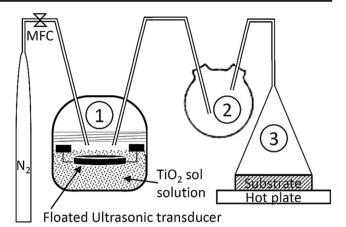


Fig. 1 Schematic illustration of the ultrasonic-assisted spray pyrolysis technique

(0.71 M). In order to control the hydrolysis of titanium(IV) butoxide precursor, pH of final solution was adjusted to 2.1 by addition of HCl solution (0.01 M). After 2 h of stirring, the obtained solution was poured into flask 1. As Fig. 1 shows, a piezoelectric ultrasonic transducer was floated on the surface of the TiO₂ sol solution, and by generation of ultrasonic waves sprayed the solution as small droplets which were carried by N₂ gas (with a flow rate of 200 ml/min) into flask 2. Inside flask 2, large droplets were separated from the small ones by sedimentation which results in the improving of the monodispersity of the obtained thin films. In flask 3 with collision of the migrated droplets to hot glass substrate (at 400 °C), they are thermally decomposed to form TiO₂ thin film. The deposition time is 30 min. The preparation procedure of S-doped TiO₂ thin films (with 1%wt S) is the same as that of the TiO_2 thin films except that 41 mg thiourea was added into the 30 ml of ethanolic solution of titanium(IV) butoxide (0.71 M).

Characterization

X-ray diffraction (XRD) patterns of the prepared thin films have been recorded by a STOE Stadi diffractometer equipped with Cu-K α irradiation ($\lambda = 1.54018$ Å). Photoluminescence (PL) emission spectra of the prepared samples were determined using Cary Eclipse fluorescence spectrophotometer (Varian, Inc., USA) at room temperature, with an excitation wavelength of 300 nm. Raman spectra of the samples were obtained using T64000-HORIABA Jobin Yvon Raman spectrometer equipped with an argon ion laser (514 nm). FTIR spectra of the samples were recorded using Brucker V33 spectrometer. The surface morphology and EDS (energy-dispersive X-ray spectroscopy) elemental analysis of the thin films were examined using MIRA3 TESCAN field emission scanning electron microscope (FESEM) (Czech Republic). Ultraviolet–visible (UV–vis) absorption and transmission spectra of the samples were recorded using Cary 100 Bio spectrophotometer (Varian, Inc., USA).

Evaluation of the visible-light photocatalytic activity of the thin films

The visible-light photocatalytic activity of the prepared thin film was examined by measuring the photocatalytic degradation of MB (as a model of organic dyes). Five milliliters of the dye solution with an initial concentration of 10 µM was added to a cuvette containing a thin-film sample with an active surface area of 2 cm^2 . Then the cuvette was sealed with glass to prevent solution evaporation. Before irradiation, the reaction solution was stirred in the dark condition for about 12 h to achieve an adsorption-desorption equilibrium. Afterward, a 570-W Xenon lamp (OSRAM Co) as visible-light source was placed at 15 cm from the reaction solution along with L41 UV cutoff filter (Kenko Co.), and the solution was irradiated at room temperature. At given time intervals, the samples were taken out by a syringe and the remaining concentration of the dye was measured using a Cary 100 Bio spectrophotometer (Varian).

Results and discussion

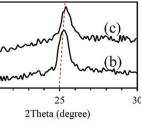
Characterization

XRD

The crystalline structure of the TiO₂ and S-doped TiO₂ thin films was analyzed by X-ray diffraction (XRD) (Fig. 2). In XRD patterns of these samples, the 2θ peaks located at 25.3°, 37.7°, 47.9°, 54.1°, 55.1°, and 62.8° are consistent with anatase lattice planes of (101), (004), (200), (105), (211), and (204) respectively (JCPDS card No. 21-1272). Therefore, both the TiO₂ and S-doped TiO₂ thin films have anatase crystal structure and presence of S element does not interfere in the crystal structure of TiO₂. The TiO₂ sample shows sharper XRD peaks (indicating a higher crystallinity) than S-doped TiO₂ thin film, and as shown in inset of Fig. 2, there is a slight shift and broadening in the (101) XRD peak of the S-doped TiO₂ sample. Presence of sulfur dopant in the lattice of TiO₂ may disorder the TiO₂ crystalline structure which results in the defect formation in the S-doped TiO₂ [34]. The X-ray diffraction patterns of the thin films show the amorphous structure to some extent, which could be related to the amorphous nature of glass substrate or presences of defects and vacancies in the films.

Raman spectroscopy

Raman spectroscopy can be used to identify trace amounts of the different crystal phases of TiO₂ [35]. Figure 3 shows room-temperature Raman spectra of the prepared samples.



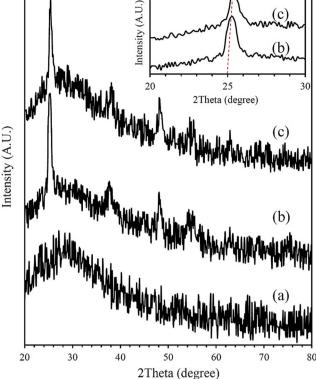


Fig. 2 XRD patterns of (a) glass substrate, (b) TiO₂, and (c) S-doped TiO2 thin-film samples

Generally, the anatase TiO₂ exhibits four major Raman active modes at Eg (144, 197, and 639 cm^{-1}), B1g (399 cm^{-1}), and A1g (519 cm^{-1}) [36, 37]. In the Raman spectra of TiO₂ and Sdoped TiO₂ thin films, all of these active modes can be identified, and there is no peak related to rutile phase of TiO₂. Hence, anatase is the dominant phase in the prepared thin films. As shown in the inset of Fig. 3, compared to the Raman spectrum of TiO₂, in Raman spectrum of S-doped TiO_2 sample, the peak located at 144.3 cm⁻¹ shifts to 146.6 cm⁻¹, indicating that introduction of S dopant in the

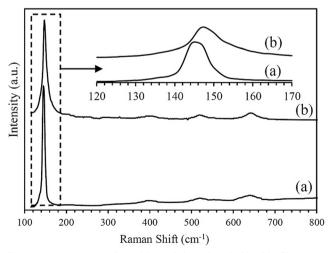


Fig. 3 Raman spectra of (a) TiO₂, and (b) S-doped TiO₂ thin films

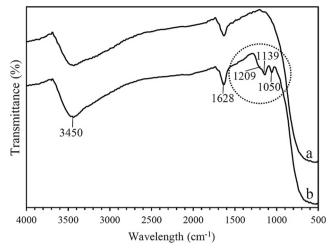


Fig. 4 FTIR spectra of (a) TiO_2 , and (b) S-doped TiO_2 thin films

crystal structure of TiO_2 increases the number of surface oxygen vacancies and defects [38].

FTIR

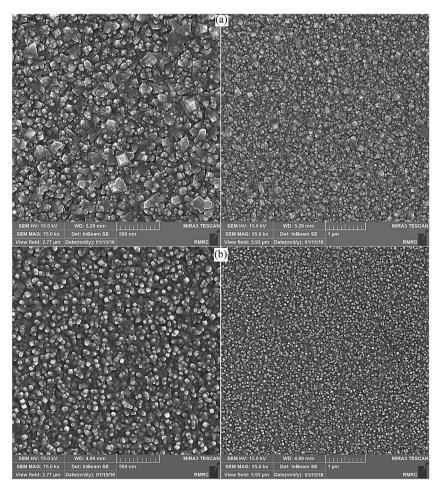
The presences of different functional groups in the synthesized thin films were confirmed from FTIR spectroscopy studies. FTIR

Fig. 5 FESEM images of a TiO_2 , and b S-doped TiO_2 thin films

spectra of the undoped and S-doped TiO₂ thin films are presented in Fig. 4. Because of the stretching and bending vibrations of the OH group of the adsorbed water, two obvious peaks at 3450 cm⁻¹ and 1628 cm⁻¹ are observed in FTIR spectra of both TiO₂ and S-doped TiO₂ thin films. The broad intense band in the range of 500–800 cm⁻¹ is due to the vibrations of Ti–O, and O– Ti–O bonds [39]. Compared to the FTIR spectrum of TiO₂, three additional absorbance peaks at about 1050, 1139, and 1209 cm⁻¹ are seen in the FTIR spectrum of S-doped TiO₂ thin film, which are ascribed to the vibration of S–Ti and Ti–O–S bonds and further confirm the presence of S in the TiO₂ lattice [37, 40].

SEM

Surface morphology of the synthesized thin films was characterized by FESEM and Fig. 5 shows FESEM images of the samples at different magnifications. Nanostructures clearly can be seen in the surface of both TiO_2 and S-doped TiO_2 thin films. As Fig. 5a indicates, irregular-shaped nanoparticles are observed in the structure of TiO_2 thin film. However, in the SEM images of the S-doped TiO_2 thin film (Fig. 5b), semi-cubic nanostructures are present at the surface of this sample, in which the size of these nanostructures is about 60 nm. Both TiO_2 and S-doped TiO_2 thin



films have high monodispersity and uniformity, and S-doped TiO_2 thin film has higher monodispersity.

Figure 6 indicates EDS spectra of the undoped and S-doped TiO₂ thin films. Besides the peaks related to TiO₂, the EDS spectra of S-doped TiO₂ thin film displays two additional peaks at about 2.05 and 2.3 keV related to the K α and K β lines of S element. Presence of other elements is related to the soda-lime type of glass which was used as substrate.

Photoluminescence

The photocatalytic activity of the semiconductor photocatalyst greatly depends on the separation and transfer ability for photoinduced electron-hole pairs. For an irradiated semiconductor sample, the photoluminescence (PL) intensity is directly related to the electron-hole recombination rate and the high electron-hole recombination rate results in the high PL intensity, and the low photocatalytic performance [41]. Therefore, the efficiency of charge-carrier trapping in the prepared samples was investigated by PL spectroscopy. As shown in Fig. 7, the S-doped TiO_2 thin film has lower PL intensity than undoped TiO₂ suggesting an enhanced charge transfer and effective separation of electronhole pairs in S-doped TiO₂. Both oxygen vacancies and lattice defects in the structure of S-doped TiO₂ can act as charge-carrier trapping centers and thereby decrease the photoinduced electron-hole recombination rate [42, 43]. Therefore, doping of S element reduces the charge-carrier recombination rate and increases the number of photogenerated electrons and holes on TiO₂ surface [44].

Fig. 6 EDS analysis results of a TiO_2 , and b S-doped TiO_2 thinfilm samples

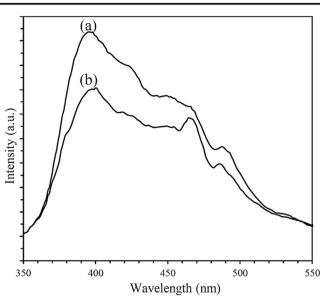
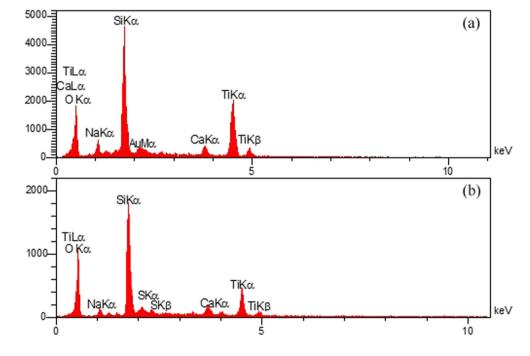


Fig. 7 PL spectra of (a) TiO₂, and (b) S-doped TiO₂ thin-film samples

Optical properties

Transparency of the prepared thin-film samples was examined via UV–Vis transmittance spectroscopy; the results are shown in Fig. 8. As this figure indicates, in the visible-light region (wavelength of 400–900 nm), the transparency of TiO₂ and S-doped TiO₂ thin films is about 81.89% and 69.73%, respectively. Therefore, because of the high uniformity and monodispersity of the prepared thin films, they have high transparency in the visible-light region.

Figure 9a depicts the UV–visible absorption spectra of the prepared thin films. Compared with undoped TiO_2 , the S-doped TiO_2 thin film has higher visible-light absorbance.



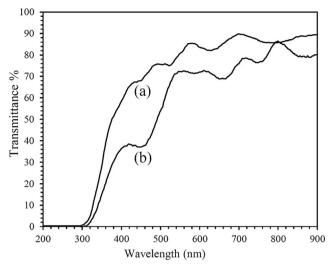


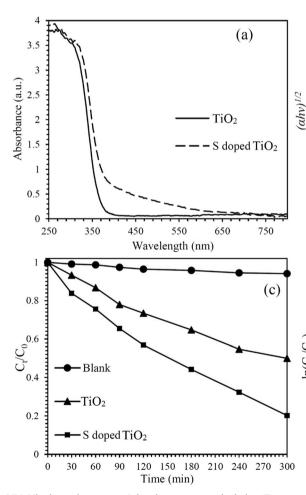
Fig. 8 Transmittance spectra of (a) TiO₂, and (b) S-doped TiO₂ thin films

Furthermore, there is a noticeable shift in the absorption edge of the S-doped TiO_2 towards longer wavelengths (red shift), indicating the narrowing of the band-gap energy of TiO_2 by S

doping. The precise value of the band-gap energy (*Eg*) for TiO₂-based semiconductors can be calculated from the intercept of the tangent line to the plots of $(\alpha h\nu)^{1/2}$ versus $h\nu$ (Tauc plots) [45, 46], as shown in Fig. 9b. The estimated band-gap energies of the undoped TiO₂ and S-doped TiO₂ thin films are 3.22 and 2.85 eV, respectively. According to the previous first-principle calculation studies, introduction of S element to the lattice of TiO₂ induces band-gap narrowing by mixing of the S 3p states with the valence band of TiO₂ [47, 48].

Photocatalytic activity

The visible-light photocatalytic degradation test of MB dye was done to survey the photocatalytic performance of the prepared samples. As Fig. 9c indicates, the visible-light degradation of MB in the absence of any thin-film photocatalyst is negligible; however, in the presence of prepared thin films, there are noticeable improvement in degradation of MB, and photocatalytic activity of S-doped TiO₂ thin film is higher than that of pure TiO₂. The kinetics of degradation of MB



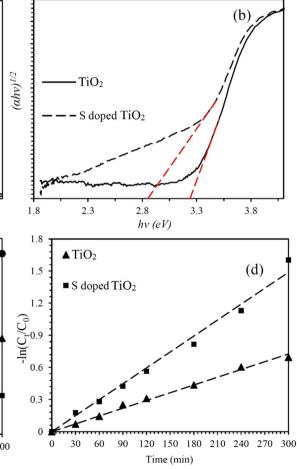


Fig.9 a UV–Vis absorption spectra, **b** band-gap energy calculation (Tauc plot) of the prepared thin films, **c** the plots of C_t/C_0 versus irradiation time for photocatalytic degradation rates of MB, and **d** calculation of the

corresponding reaction rate constants (k) for TiO₂ and S-doped TiO₂ thin films under visible-light irradiation

dye in the presences of the prepared thin films were modeled using the Langmuir–Hinshelwood (L-H) model. For low concentrations of MB, the pseudo-first-order kinetic model can be used for calculation of the reaction rate constants (k), represented by Eq. (1) [49]:

$$-\ln\left(\frac{C_t}{C_0}\right) = kt \tag{1}$$

The value of the reaction rate constants (*k*) for visible-light photocatalytic degradation of MB over TiO₂ and S-doped TiO₂ thin films can be estimated from the slope of $-\ln\left(\frac{C_t}{C_0}\right)$ versus irradiation time (*t*) plots, which Fig. 9d shows these plots. The estimated reaction rate constants for visible-light photocatalytic degradation of MB on TiO₂ and S-doped TiO₂ thin films are 0.0024 and 0.0055 min⁻¹, respectively. The low recombination rate of the photoinduced electron–hole pairs and the low band-gap energy of the S-doped TiO₂ thin film may be the reasons for the enhancement of its visible-light photocatalytic activity.

Conclusion

In summary, at the present work, nanostructured TiO₂ and Sdoped TiO₂ thin films with high transparency were deposited on glass substrate through ultrasonic-assisted spray pyrolysis technique. The prepared films were used for the visible-light photocatalytic degradation of MB dye. Both the undoped and S-doped TiO₂ have anatase crystal structure; however, there are some defect and oxygen vacancies in the S-doped sample. Based on the PL spectroscopy results, because of the defect formation in the S-doped TiO₂ thin film, this sample has lower electron-hole recombination rate than TiO₂ thin film. Furthermore, the presence of S dopants in the structure of TiO₂ results in the narrowing of the band-gap energy of TiO₂. Among the prepared thin films, the S-doped TiO₂ thin film has higher photocatalytic activity than pure TiO₂ sample for the visible-light photocatalytic degradation of MB dye.

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